## NSN 5961-01-371-2111

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 on voltage, forward voltage drop, dc
Current Rating Per Characteristic:
20.00 milliamperes source cutoff current preset and 50.00 milliamperes forward current, average peak
Power Rating Per Characteristic:
350.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0
Power Rating Per Characteristic:  350.0 milliwatts small-signal input power, common-collector preset  Maximum Operating Tempurature Per Measurement Point:  125.0 degrees celsius ambient air  Terminal Type And Quantity:  2 uninsulated wire lead  Shelf Life:  N/a  Unit Of Measure:   Demilitarization:  Yes - demil/mli  Fiig: